

Armando Majorana

List of Publications by Year in descending order

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Version: 2024-02-01

58
papers

907
citations

430874

18
h-index

477307

29
g-index

59
all docs

59
docs citations

59
times ranked

267
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|---|-----|-----------|
| 1 | A WENO-solver for the transients of Boltzmann-Poisson system for semiconductor devices: performance and comparisons with Monte Carlo methods. <i>Journal of Computational Physics</i> , 2003, 184, 498-525. | 3.8 | 120 |
| 2 | A discontinuous Galerkin solver for Boltzmann-Poisson systems in nano devices. <i>Computer Methods in Applied Mechanics and Engineering</i> , 2009, 198, 3130-3150. | 6.6 | 62 |
| 3 | A Finite Difference Scheme Solving the Boltzmann-Poisson System for Semiconductor Devices. <i>Journal of Computational Physics</i> , 2001, 174, 649-668. | 3.8 | 56 |
| 4 | Space homogeneous solutions of the Boltzmann equation describing electron-phonon interactions in semiconductors. <i>Transport Theory and Statistical Physics</i> , 1991, 20, 261-279. | 0.4 | 55 |
| 5 | DSMC method consistent with the Pauli exclusion principle and comparison with deterministic solutions for charge transport in graphene. <i>Journal of Computational Physics</i> , 2015, 302, 267-284. | 3.8 | 50 |
| 6 | 2D semiconductor device simulations by WENO-Boltzmann schemes: Efficiency, boundary conditions and comparison to Monte Carlo methods. <i>Journal of Computational Physics</i> , 2006, 214, 55-80. | 3.8 | 48 |
| 7 | Shock structure for heat conducting and viscid fluids. <i>Meccanica</i> , 1981, 16, 149-156. | 2.0 | 40 |
| 8 | A Direct Solver for 2D Non-Stationary Boltzmann-Poisson Systems for Semiconductor Devices: A MESFET Simulation by WENO-Boltzmann Schemes. <i>Journal of Computational Electronics</i> , 2003, 2, 375-380. | 2.5 | 36 |
| 9 | Cross validation of discontinuous Galerkin method and Monte Carlo simulations of charge transport in graphene on substrate. <i>Ricerche Di Matematica</i> , 2017, 66, 201-220. | 1.0 | 31 |
| 10 | Equilibrium solutions of the non-linear Boltzmann equation for an electron gas in a semiconductor. <i>Societa Italiana Di Fisica Nuovo Cimento B-General Physics, Relativity Astronomy and Mathematical Physics and Methods</i> , 1993, 108, 871-877. | 0.2 | 26 |
| 11 | Existence and uniqueness of positive solutions to a linear transport equation in a metric space. <i>Applied Mathematics Letters</i> , 1997, 10, 49-53. | 2.7 | 24 |
| 12 | Magnetoacoustic shock waves in a relativistic gas. <i>Physics of Fluids</i> , 1987, 30, 3045. | 1.4 | 23 |
| 13 | Charge transport in 1D silicon devices via Monte Carlo simulation and Boltzmann-Poisson solver. <i>COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering</i> , 2004, 23, 410-425. | 0.9 | 21 |
| 14 | Shock Structure in Relativistic Fluid-Dynamics. <i>Journal of Non-Equilibrium Thermodynamics</i> , 1985, 10, . | 4.2 | 20 |
| 15 | Simulation of Bipolar Charge Transport in Graphene by Using a Discontinuous Galerkin Method. <i>Communications in Computational Physics</i> , 2019, 26, 114-134. | 1.7 | 20 |
| 16 | Space Homogeneous Solutions of the Linear Semiconductor Boltzmann Equation. <i>Journal of Mathematical Analysis and Applications</i> , 2001, 259, 609-629. | 1.0 | 19 |
| 17 | A WENO-Solver for the 1D Non-Stationary Boltzmann-Poisson System for Semiconductor Devices. <i>Journal of Computational Electronics</i> , 2002, 1, 365-370. | 2.5 | 19 |
| 18 | A brief survey of the discontinuous Galerkin method for the Boltzmann-Poisson equations. <i>Boletín De La Sociedad Española De Matemática Aplicada</i> , 2011, 54, 47-64. | 0.9 | 19 |

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|----|--|-----|-----------|
| 19 | Charge transport and mobility in monolayer graphene. Journal of Mathematics in Industry, 2016, 7, . | 1.2 | 19 |
| 20 | Discontinuous Galerkin solver for Boltzmann-Poisson transients. Journal of Computational Electronics, 2008, 7, 119-123. | 2.5 | 18 |
| 21 | Analysis of thermal, sound, and shear waves according to a relativistic kinetic model. Physics of Fluids, 1985, 28, 1673. | 1.4 | 15 |
| 22 | Conservation laws from the Boltzmann equation describing electron-phonon interactions in semiconductors. Transport Theory and Statistical Physics, 1993, 22, 849-859. | 0.4 | 15 |
| 23 | On a four-body problem. Celestial Mechanics, 1981, 25, 267-270. | 0.1 | 13 |
| 24 | A numerical model of the Boltzmann equation related to the discontinuous Galerkin method. Kinetic and Related Models, 2011, 4, 139-151. | 0.9 | 12 |
| 25 | Space Homogeneous Solutions to the Cauchy Problem for Semiconductor Boltzmann Equations. SIAM Journal on Mathematical Analysis, 1997, 28, 1294-1308. | 1.9 | 11 |
| 26 | Deterministic Simulation of the Boltzmann-Poisson System in GaAs-Based Semiconductors. SIAM Journal of Scientific Computing, 2006, 27, 1981-2009. | 2.8 | 11 |
| 27 | Trend to equilibrium of electron gas in a semiconductor according to the Boltzmann equation. Transport Theory and Statistical Physics, 1998, 27, 547-571. | 0.4 | 9 |
| 28 | Propagation of infinitesimal disturbances in a gas according to a relativistic kinetic model. Meccanica, 1984, 19, 175-181. | 2.0 | 8 |
| 29 | Structure of shock waves in relativistic simple gases. Physics of Fluids, 1988, 31, 1064. | 1.4 | 8 |
| 30 | A Discontinuous Galerkin Solver for Full-Band Boltzmann-Poisson Models. , 2009, , . | | 8 |
| 31 | Continuous Solutions of a Nonlinear Integral Equation on an Unbounded Domain. Journal of Integral Equations and Applications, 1994, 6, . | 0.6 | 8 |
| 32 | DSMC versus WENO-BTE: A double gate MOSFET example. Journal of Computational Electronics, 2007, 5, 471-474. | 2.5 | 7 |
| 33 | Analysis of thermal and shear waves according to BKG kinetic model. Zeitschrift Fur Angewandte Mathematik Und Physik, 1985, 36, 699-711. | 1.4 | 6 |
| 34 | Analytical solutions of the Rankine-Hugoniot relations for a relativistic simple gas. Il Nuovo Cimento B, 1987, 98, 111-118. | 0.1 | 5 |
| 35 | STATIONARY SOLUTIONS OF HYDRODYNAMIC MODELS FOR SEMICONDUCTOR DEVICE SIMULATION. COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering, 1993, 12, 81-93. | 0.9 | 5 |
| 36 | Discontinuous Galerkin Solver for the Semiconductor Boltzmann Equation. , 2007, , 257-260. | | 5 |

| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 37 | Finite amplitude water waves above a sloping beach. <i>Wave Motion</i> , 1985, 7, 229-233. | 2.0 | 4 |
| 38 | Relativistic relaxation models for a simple gas. <i>Journal of Mathematical Physics</i> , 1990, 31, 2042-2046. | 1.1 | 4 |
| 39 | Numerical Solutions of the Spatially Homogeneous Boltzmann Equation for Electrons in n-Doped Graphene on a Substrate. <i>Journal of Computational and Theoretical Transport</i> , 2017, 46, 176-185. | 0.8 | 4 |
| 40 | Shock structure in an ultrarelativistic gas. <i>Meccanica</i> , 1990, 25, 77-82. | 2.0 | 3 |
| 41 | The Velocity Overshoot in Semiconductors According to a Transport Model Derived from the Boltzmann Equation. <i>Transport Theory and Statistical Physics</i> , 2000, 29, 805-823. | 0.4 | 3 |
| 42 | A Uniqueness Theorem for $y_{ij}^{1/2} = f(x, y)$, $y(x_0) = y_0$. <i>Proceedings of the American Mathematical Society</i> , 1991, 111, 215. | 0.8 | 2 |
| 43 | On the Cauchy problem for spatially homogeneous semiconductor Boltzmann equations: existence and uniqueness. <i>Annali Di Matematica Pura Ed Applicata</i> , 2005, 184, 275-296. | 1.0 | 2 |
| 44 | Discontinuous Galerkin methods for the Boltzmann-Poisson systems in semiconductor device simulations. , 2011, , . | | 2 |
| 45 | Discontinuous Galerkin deterministic solvers for a Boltzmann-Poisson model of hot electron transport by averaged empirical pseudopotential band structures. <i>Computer Methods in Applied Mechanics and Engineering</i> , 2017, 321, 209-234. | 6.6 | 2 |
| 46 | Finite moment equations for a relativistic simple gas. <i>Journal of Mathematical Physics</i> , 1988, 29, 987-989. | 1.1 | 1 |
| 47 | A uniqueness theorem for $\varphi \in \mathcal{T}^m = \mathcal{T}(\varphi, \varphi), \varphi(\varphi, \epsilon) = \varphi \hat{a}, \epsilon$. <i>Proceedings of the American Mathematical Society</i> , 1991, 111, 215-220. | 0.8 | 1 |
| 48 | A boundary value problem for a kinetic model describing electron flow in a semiconductor. <i>Mathematical Methods in the Applied Sciences</i> , 2000, 23, 735-750. | 2.3 | 1 |
| 49 | High field mobility and diffusivity of an electron gas in silicon devices. <i>COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering</i> , 2002, 21, 31-44. | 0.9 | 1 |
| 50 | Performance of a discontinuous Galerkin solver for semiconductor Boltzmann equations. , 2010, , . | | 1 |
| 51 | Numerical solutions to a microcontinuum model using WENO schemes. <i>Continuum Mechanics and Thermodynamics</i> , 2020, 32, 945-957. | 2.2 | 1 |
| 52 | Approximate explicit stationary solutions to a Vlasov equation for planetary rings. <i>Kinetic and Related Models</i> , 2017, 10, 467-479. | 0.9 | 1 |
| 53 | A fast approach to discontinuous Galerkin solvers for Boltzmann-Poisson transport systems for full electronic bands and phonon scattering. , 2012, , . | | 0 |
| 54 | Deterministic solutions of the Boltzmann equation for charge transport in graphene on substrates. , 2016, , . | | 0 |

| # | ARTICLE | IF | CITATIONS |
|----|---|-----|-----------|
| 55 | Deterministic numerical solutions to a semi-discrete Boltzmann equation. AIP Conference Proceedings, 2019, , . | 0.4 | 0 |
| 56 | HOW TO TACKLE THE BOLTZMANN EQUATION FOR INDUSTRIAL SEMICONDUCTOR DEVICE SIMULATION. , 2005, , . | | 0 |
| 57 | Deterministic Solutions of the Transport Equation for Charge Carrier in Graphene. Mathematics in Industry, 2016, , 741-748. | 0.3 | 0 |
| 58 | A BGK model for charge transport in graphene. Communications in Applied and Industrial Mathematics, 2019, 10, 153-161. | 0.3 | 0 |